

■ **INTRODUCTION**

The CE8809 Series is a series of high-precision voltage detectors with a built-in delay time generator of fixed time, developed using CMOS process.

The detection voltage is fixed internally, with an accuracy of $\pm 2.0\%$. Internal oscillator and counter timer can delay the release signal without external parts, delay times 200 ms. Two output forms, NMOS open-drain and CMOS output are available.

■ **APPLICATIONS**

- Memory battery back-up circuits
- Power-on reset circuits
- Power failure detection
- Power monitor for portable equipment such as notebook computers, digital cameras, PDA, and cellular phones.
- Constant voltage power monitors for cameras, video equipment and communication devices.
- Power monitor for microcomputers and reset for CPUs.

■ **FEATURES**

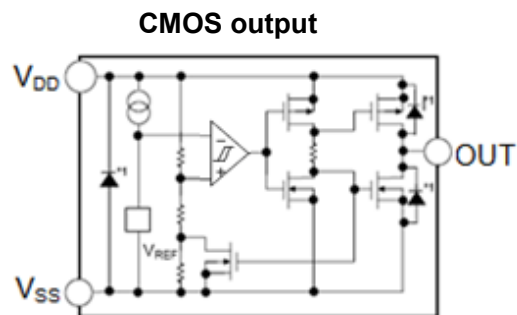
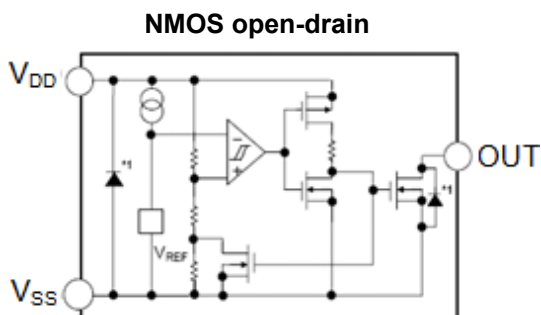
- Ultra-low current consumption:
0.9 μ A@3.5V(Typ.)
- High-precision detection voltage: $\pm 2.0\%$
- Hysteresis characteristics: $-V_{DET} \times 5\%$ (Typ.)
- Operating voltage range: 0.95V to 7.0V
- Detection voltage: 1.5V to 6.0V (10mV step)
- Delay time: 210 ms (Typ.)
- Output forms:
NMOS open-drain output (Active Low)
CMOS output (Active Low)

■ **ORDER INFORMATION**

CE8809①②③④⑤

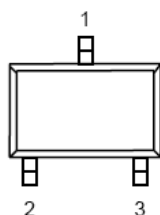
DESIGNATOR	SYMBOL	DESCRIPTION
①	C	CMOS
	N	NMOS open drain
②③④	Integer	Detection Voltage (1.50V~6.00V), “④”elide when it is “0” e.g. 3.0V=②:3, ③:0 2.93V=②:2, ③:9, ④:3
⑤	M/MA	封装形式: SOT-23-3
	P	封装形式: SOT-89-3
	T/TA	封装形式: TO-92
	N/NA	封装形式: SOT-343 (SC-82)
	E	封装形式: SOT-23-6
	MB/MAB	封装形式: SOT-23

■ **BLOCK DIAGRAMS**



■ PIN CONFIGURATION

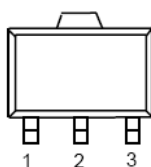
SOT-23-3
Top view



CE8809 Series (SOT-23/SOT-23-3)

PIN NO.	M/MB	MA/MAB	FUNCTION
1	V _{DD}	V _{DD}	Voltage input pin
2	V _{OUT}	-	Voltage detection output pin
	-	V _{SS}	Ground
3	V _{SS}	-	Ground
	-	V _{OUT}	Voltage detection output pin

SOT-89-3
Top view



CE8809 Series (SOT-89-3)

PIN NO.	P	FUNCTION
1	V _{OUT}	Voltage detection output pin
2	V _{DD}	Voltage input pin
3	V _{SS}	Ground

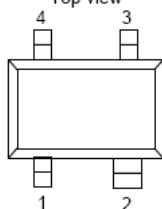
TO-92
Bottom view



CE8809 Series (TO-92)

PIN NO.	T	FUNCTION
1	V _{OUT}	Voltage detection output pin
2	V _{DD}	Voltage input pin
3	V _{SS}	Ground

SOT343(SC-82)
Top view

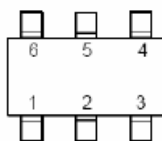


CE8809Series (SOT343)

PIN NO.	N	NA	FUNCTION
1	V _{OUT}	-	Voltage detection output pin
	-	V _{DD}	Voltage input pin
2	V _{DD}	-	Voltage input pin
	-	V _{SS}	Ground
3	NC	-	No Connection
4	V _{SS}	-	Ground
	-	V _{OUT}	Voltage detection output pin

CE8809 Series (SOT23-6)

(TOP VIEW)



SOT-26

PIN NO	E	FUNCTION
1	NC	No Connection
2	VSS	Ground
3	VOUT	Voltage detection output pin
4	VDD	Voltage input pin
5	NC	No Connection
6	NC	No Connection

■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNITS
Power supply voltage		V _{DD}	V _{SS} -0.3 ~ V _{SS} +8	V
Output voltage		V _{OUT}	V _{SS} -0.3 ~ V _{SS} +8	V
Power dissipation	SOT-23-3	PD	250	mW
	SOT-89		500	mW
	TO-92		500	mW
	SOT-343		250	mW
Operating ambient temperature		T _{opr}	-40 ~ +85	°C
Storage temperature		T _{stg}	-40 ~ +125	°C
Soldering Temperature & Time		T _{solder}	260°C, 10s	

■ ELECTRICAL CHARACTERISTICS

(Ta=25°C, unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Detection voltage*1	-V _{DET}	—		-V _{DET(S)} ×0.98	-V _{DET(S)}	-V _{DET(S)} ×1.02	V
Hysteresis width	V _{HYS}	—		0.02× -V _{DET(S)}	0.05× -V _{DET(S)}	0.08× -V _{DET(S)}	V
Current consumption	I _{SS}	V _{DD} = -V _{DET} +0.5V	CE8809C/N20~26	—	1.0	2.0	uA
			CE8809 C/N 26~39	—	1.2	2.5	uA
			CE8809 C/N 39~60	—	1.5	3.0	uA
Operating voltage	V _{DD}	—		0.95	—	7	V
Output current	I _{OUT}	NMOS: V _{OUT} =0.5 V V _{DD} =-V _{DET} -0.5 V	CE8809 C/N 20~26	3.0	13.0	—	mA
			CE8809 C/N 26~39	3.0	15.0	—	mA
			CE8809 C/N 39~60	3.0	18.0	—	mA
		PMOS: V _{DD} -V _{OUT} =0.5 V V _{DD} =-V _{DET} +0.5 V	CE8809 C/N 20~26	1.5	4.0	—	mA
			CE8809 C/N 26~39	1.5	6.0	—	mA
			CE8809 C/N 39~60	1.5	8.0	—	mA
Leakage current	I _{LEAK}	Only for NMOS open-drain output products, V _{DD} =8.0 V, V _{OUT} =8.0 V		—	—	1	uA
temperature coefficient		Ta=-40°C ~+85°C		—	±120	±360	ppm/°C
Delay time	T _{PLH}			130	210	290	ms

*1. -VDET: Actual detection voltage value, -VDET(S): Specified detection voltage value

■ FUNCTIONAL DESCRIPTION

1. When a voltage higher than the release voltage ($+V_{DET}$) is applied to the voltage input pin (V_{DD}), the voltage will gradually fall. When a voltage higher than the detect voltage ($-V_{DET}$) is applied to V_{DD} , output (V_{OUT}) will be equal to the input at V_{DD} .

Note that high impedance exists at V_{OUT} with the N-channel open drain configuration. If the pin is pulled up, V_{OUT} will be equal to the pull up voltage.

2. When V_{DD} falls below $-V_{DET}$, V_{OUT} will be equal to the ground voltage (V_{SS}) level (detect state).

Note that this also applies to N-channel open drain configurations.

3. When V_{DD} falls to a level below that of the minimum operating voltage (V_{MIN}) output will become unstable.

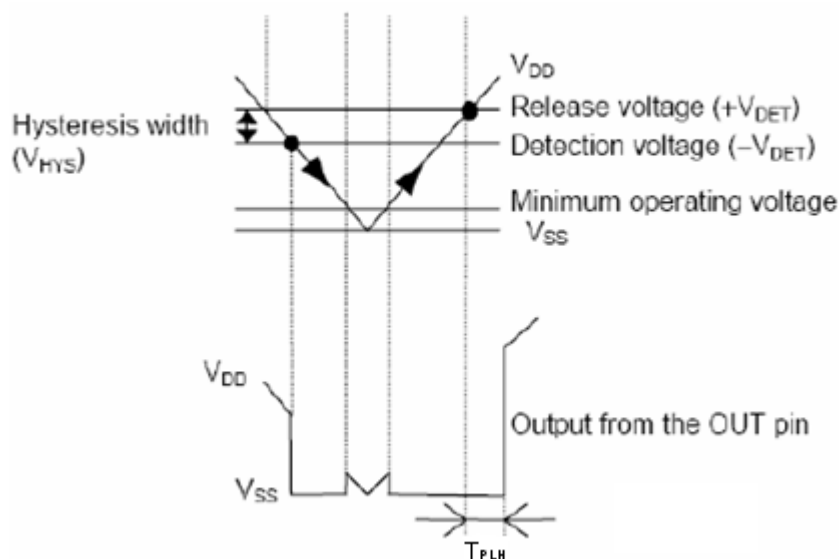
Because the output pin is generally pulled up with N-channel open drain configurations, output will be equal to pull up voltage.

4. When V_{DD} rises above the V_{SS} level (excepting levels lower than minimum operating voltage), V_{OUT} will be equal to V_{SS} until V_{DD} reaches the $+V_{DET}$ level.

5. Although V_{DD} will rise to a level higher than $+V_{DET}$, V_{OUT} maintains ground voltage level via the delay circuit.

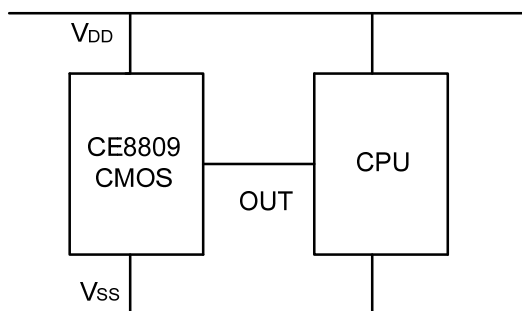
6. Following transient delay time, V_{DD} will be output at V_{OUT} .

Note that high impedance exists with the N-channel open drain configuration and that voltage will be dependent on pull up

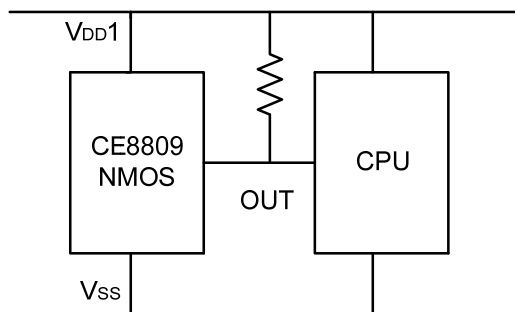
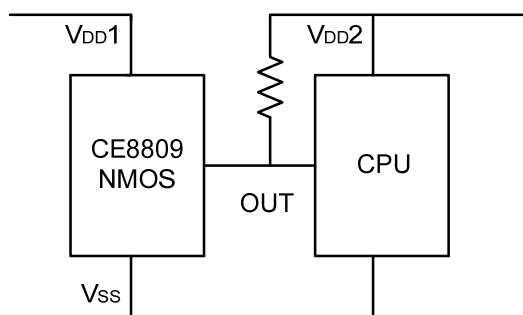


■ TYPICAL APPLICATION CIRCUITS

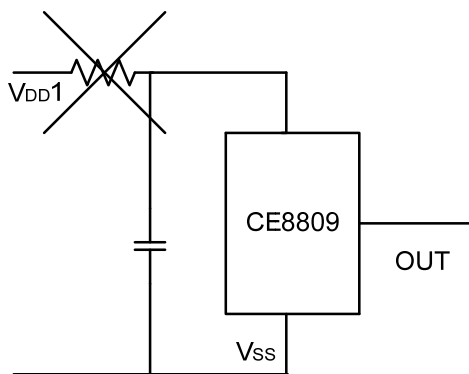
1、CMOS output:



2、NMOS open-drain

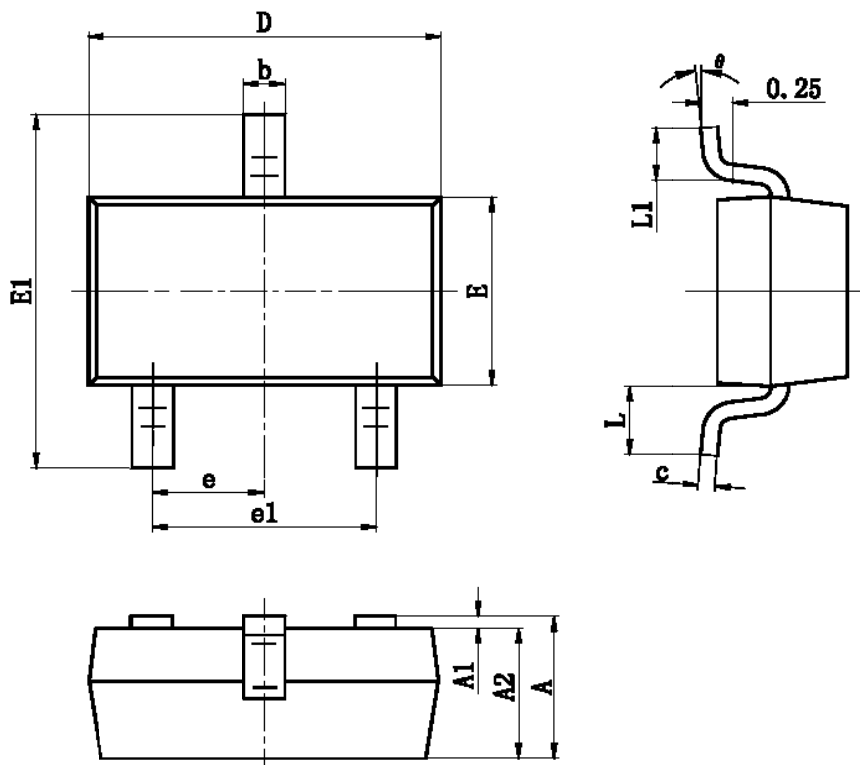


3. Forbidden Circuits



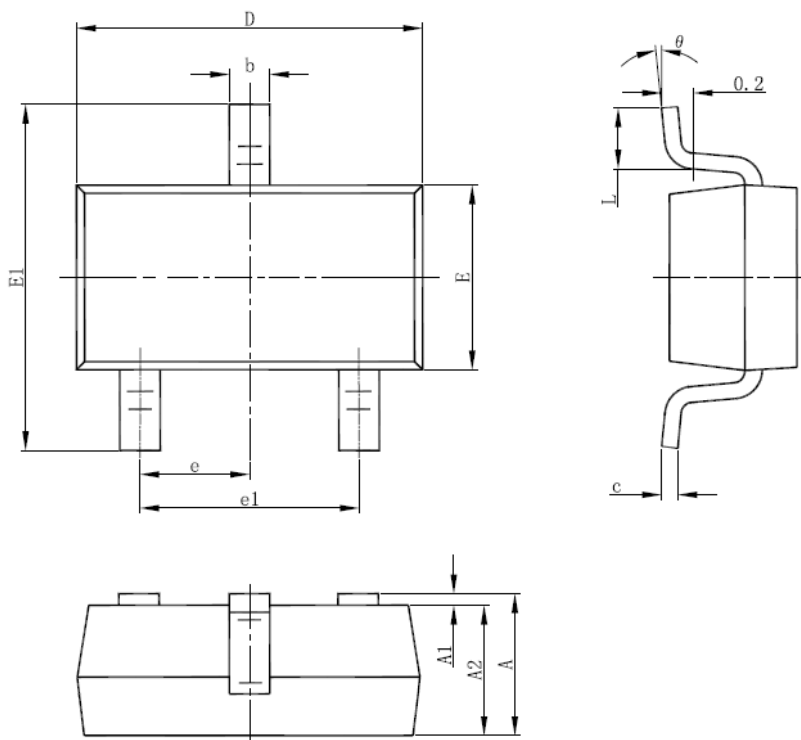
■ PACKAGING INFORMATION

- SOT-23



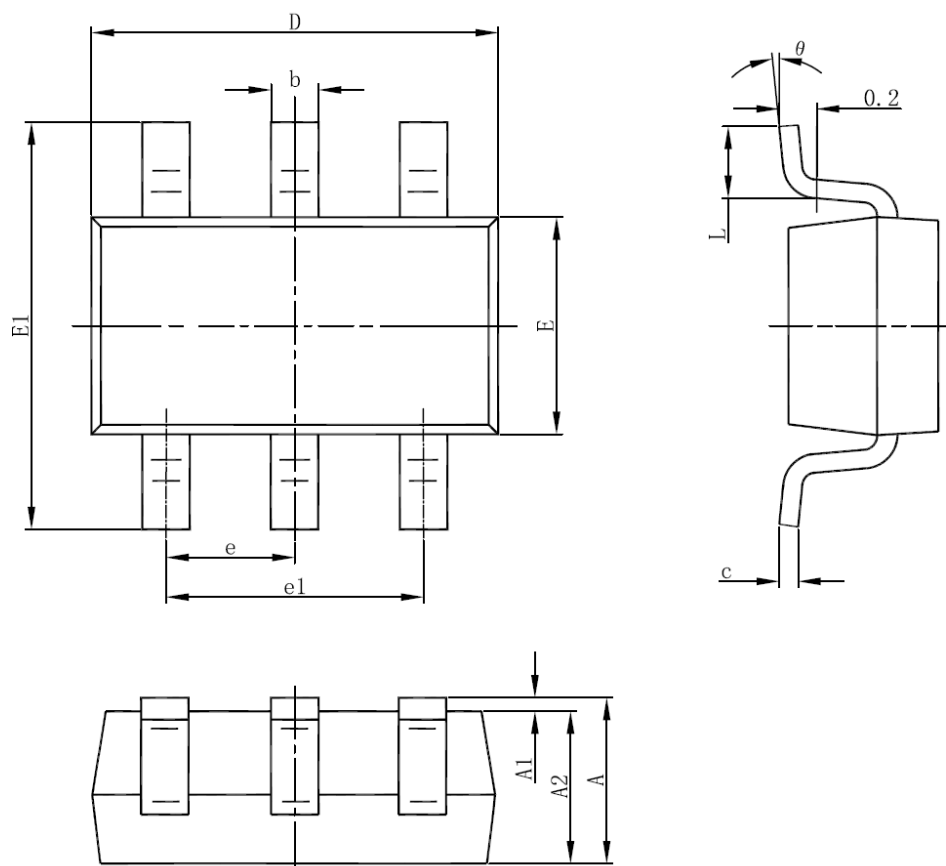
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	6°

• SOT-23-3



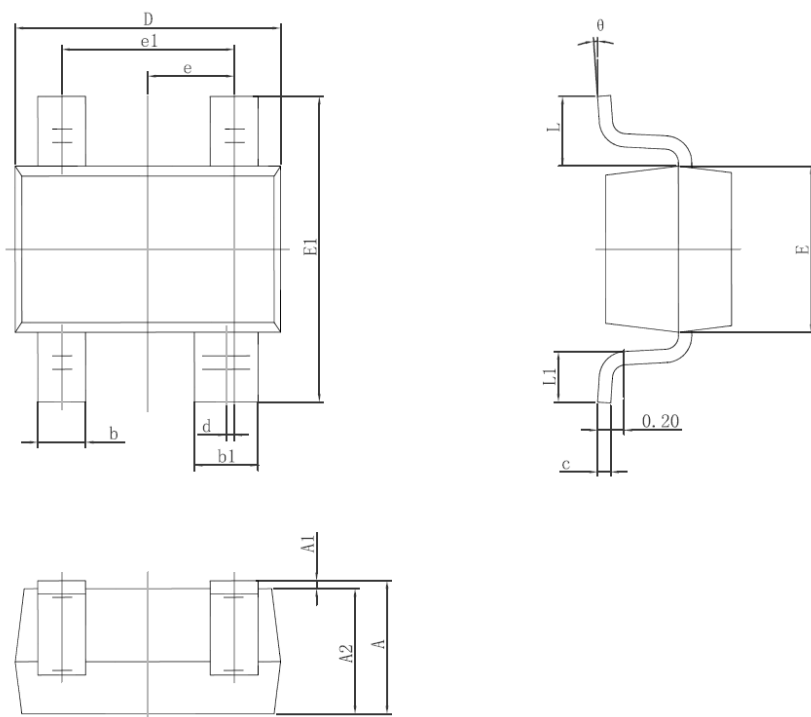
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

• SOT-23-6



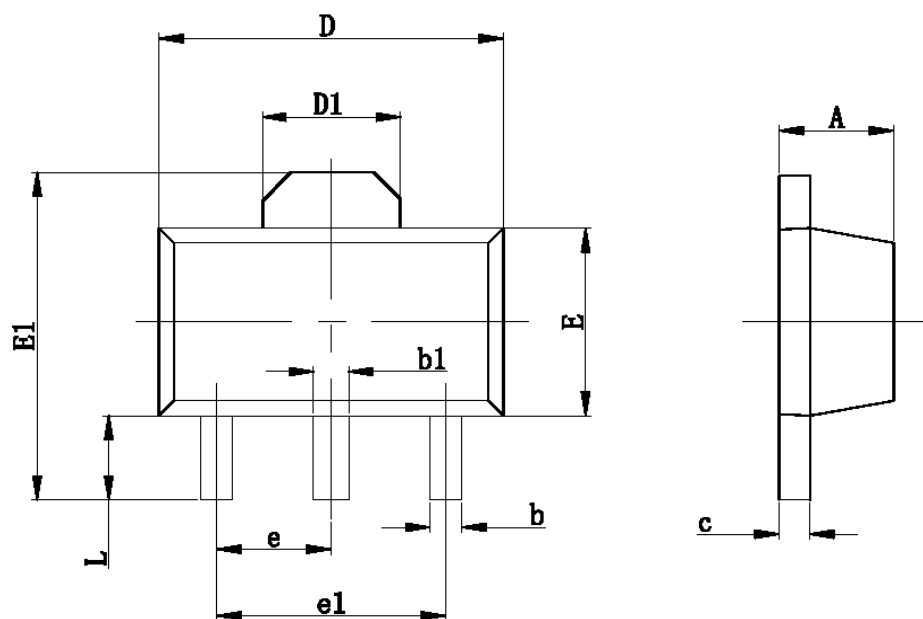
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

• SOT-343



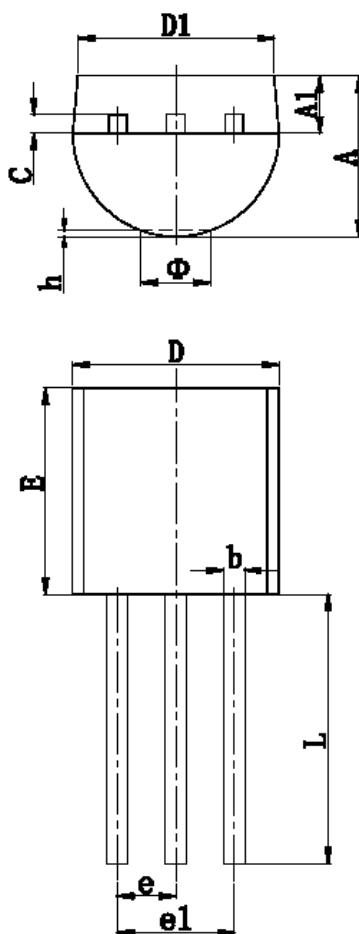
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.250	0.400	0.010	0.016
b1	0.350	0.500	0.014	0.020
c	0.080	0.150	0.003	0.006
d	0.050 TYP.		0.002 TYP.	
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650 TYP.		0.026 TYP.	
e1	1.200	1.400	0.047	0.055
L	0.525 REF.		0.021 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

- SOT-89-3



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.197
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF		0.061 REF	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500 TYP		0.060TYP	
e1	3.000 TYP		0.118TYP	
L	0.900	1.200	0.035	0.047

- TO-92



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.400	4.700	0.173	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP		0.050 TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015

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